

FORM PTO-1449  INFORMATION DISCLOSURE CITATION IN AN APPLICATION		DOCKET NUMBER SLA0805	APPLICATION NUMBER
		APPLICANT Wei Gao, and Yoshi Ono	
		FILING DATE: September 30, 2003	GROUP ART UNIT
U.S. PATENT DOCUMENTS			
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME
FOREIGN PATENT DOCUMENTS			
	DOCUMENT NUMBER	DATE	COUNTRY/NAME
OTHER DOCUMENTS			
GM	Article entitled: Nb Oxide Thin Film Resistors; by Wilson <i>et al.</i> , published in IEEE Transactions on Applied Superconductivity, Vol.9 No. 2, June 1999.		
GM	Article entitled: Properties of Ru-Ta Alloys as Gate Electrodes For NMOS and PMOS Silicon Devices, by Zhong <i>et al.</i> , IEEE, 2001		
GM	Article entitled: Tunable Work Function Molybdenum Gate Technology for FDSOI-CMOS, by Ranade <i>et al.</i> , IEEE 2002		
GM	Article entitled: A Phase Map for Sputter Deposited Niobium Oxides, by Lee and Aita, pub in the Journal of Applied Physics, Vol. 70, No. 4, 15 August 1991		
EXAMINER <i>Thomas M. Gao</i>		DATE CONSIDERED <i>11/3/04</i>	